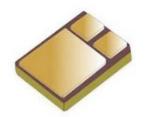


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Features

- JANS and JANSR Qualified to MIL-PRF-19500/560
- JEDEC Registered 2N5154
- · Lightweight & Low Power
- Ideal for Space, Military, and Other High Reliability Applications
- Surface Mount U3 Package



Electrical Characteristics

Parameter	Test Conditions	Symbol	Units	Min.	Max.				
Off Characteristics									
Collector - Emitter Breakdown Voltage	I _C = 50 mAdc	V _{(BR)CEO}	Vdc	100	_				
Collector - Emitter Cutoff Current	$V_{CE} = 100 \text{ Vdc}$ $V_{CE} = 90 \text{ Vdc}, V_{BE} = 1.5 \text{ Vdc}$	I _{CEO}	μAdc	_	100 1.0				
Collector - Base Cutoff Current	V _{CB} = 100 Vdc	I _{CBO}	μAdc		1.0				
Emitter - Base Cutoff Current	V _{EB} = 6.0 Vdc	I _{EBO}	μAdc	_	100				
On Characteristics ¹									
Forward Current Transfer Ratio	I_C = 0.5 Adc, V_{CE} = 2.0 Vdc I_C = 2.0 Adc, V_{CE} = 2.0 Vdc I_C = 5.0 Adc, V_{CE} = 2.0 Vdc	H _{FE}	-	60 60 40	 240 				
Collector - Emitter Saturation Voltage	$I_C = 2.0 \text{ Adc}, I_B = 0.2 \text{ Adc}$ $I_C = 5.0 \text{ Adc}, I_B = 0.5 \text{ Adc}$	V _{CE(SAT)}	Vdc	_	0.7 1.2				
Emitter - Base Saturation Voltage	I_C = 2.0 Adc, I_B = 0.2 Adc I_C = 5.0 Adc, I_B = 0.5 Adc	V _{BE(SAT)}	Vdc	_	1.2 1.8				
Dynamic Characteristics	Dynamic Characteristics								
Magnitude of Common Emitter Small-Signal Short-Circuit Forward Current Transfer Ratio	$I_C = 0.5 \text{ Adc}, V_{CE} = 10.0 \text{ Vdc}, f = 10 \text{ mHz}$	H _{FE}	-	3	15				
Output Capacitance	V _{CB} = 10 Vdc, I _E = 0, 100 kHz ≤ f ≤ 1 MHz	C _{OBO}	pF	_	250				
Input Capacitance	V _{BE} = 2 Vdc, I _C = 0, 100 kHz ≤ f ≤ 1 MHz	C _{IBO}	pF	_	1000				
Safe Operating Area									

 $\begin{array}{lll} \text{DC Tests:} & & & & & & & & & \\ \text{Test 1:} & & & & & & & \\ \text{Test 2:} & & & & & & \\ \text{Test 3:} & & & & & & \\ \end{array} \begin{array}{ll} & & & & & & \\ \text{Test 2:} & & & & & \\ \text{V}_{\text{CE}} = 2 \text{ Vdc, I}_{\text{C}} = 5 \text{ Adc} \\ \text{V}_{\text{CE}} = 5 \text{ Vdc, I}_{\text{C}} = 2 \text{ Adc} \\ \text{V}_{\text{CE}} = 90 \text{ Vdc, I}_{\text{C}} = 55 \text{ mAdc} \\ \end{array}$

1. Pulse Test: Pulse Width = 300 μ s, Duty Cycle \leq 2.0%.



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Absolute Maximum Ratings¹

Ratings	Symbol	Value
Collector - Emitter Voltage	V_{CEO}	100 Vdc
Collector - Base Voltage	V_{CBO}	100 Vdc
Emitter - Base Voltage	V _{EBO}	6 Vdc
Base Current	I _B	1 Adc
Collector Current	Ic	5 Adc
Total Power Dissipation @ T _A = 25°C @ T _C = 25°C	P _T	1.0 W 75 W
Operating & Storage Temperature Range	T _{OP} , T _{STG}	-65°C to +200°C

^{1.} Derate linearly 434 mW/°C for T_C > 25°C

Thermal Characteristics

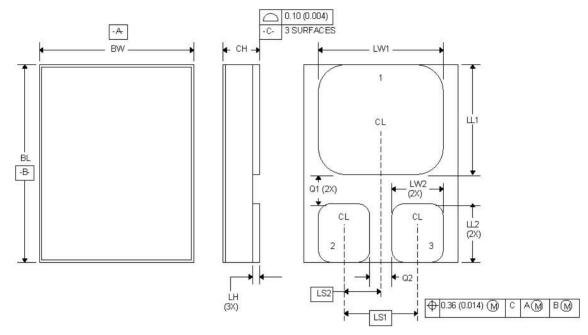
Characteristics	Symbol	Max. Value
Thermal Resistance, Junction to Case	$R_{ heta JC}$	2.3°C/W



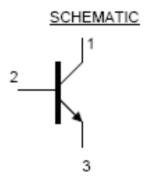
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Outline Drawing (U3)



- 1. Dimensions are in inches.
- Millimeters are given for general information only.
 In accordance with ASME Y14.5M, diameters are equivalent to φx symbology.
- 4. Terminal 1 collector, terminal 2 -base, terminal 3 emitter.



	Dimensions					
Ltr	Ltr Inches		Millimeters			
	Min.	Max.	Min.	Max.		
BL	0.395	0.405	10.03	10.29		
BW	0.291	0.301	7.40	7.65		
CH	0.1085	0.1205	2.76	3.06		
LH	0.010	0.020	0.25	0.51		
LW ₁	0.281	0.291	7.14	7.39		
LW ₂	0.090	0.100	2.29	2.54		
LL ₁	0.220	0.230	5.59	5.84		
LL ₂	0.115	0.125	2.92	3.18		
LS ₁	0.150 BSC		3.81 BSC			
LS ₂	0.075 BSC		1.91 BSC			
Q ₁	0.030	-	0.762	-		
Q_2	0.030	-	0.762	-		

2N5339U3



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